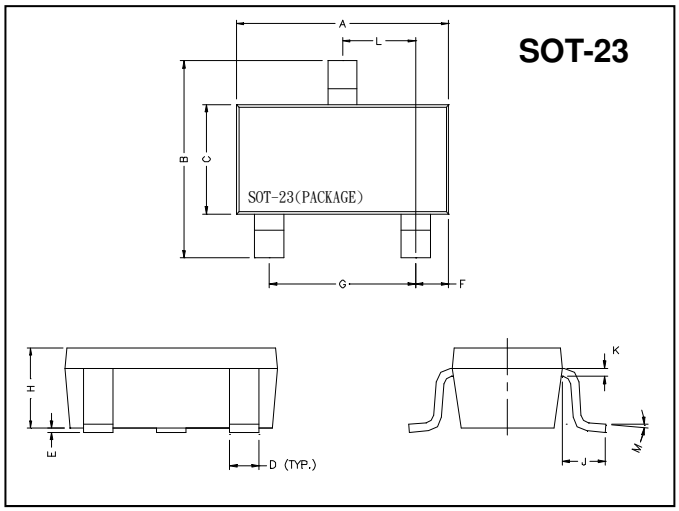
G400SD

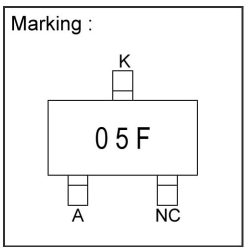
SURFACE MOUNT, SCHOTTKY BARRIER DIODE
VOLTAGE 40V, CURRENT 0.5A

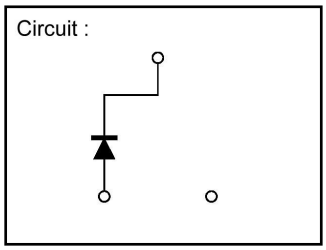
Description

The G400SD is high frequency rectification for switching power supply.

Package Dimensions







REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	2.70	3.10	G	1.90 REF.	
B	2.40	2.80	H	1.00	1.30
C	1.40	1.60	K	0.10	0.20
D	0.35	0.50	J	0.40	-
E	0	0.10	L	0.85	1.15
F	0.45	0.55	M	0°	10°

Absolute Maximum Ratings at T_A = 25℃

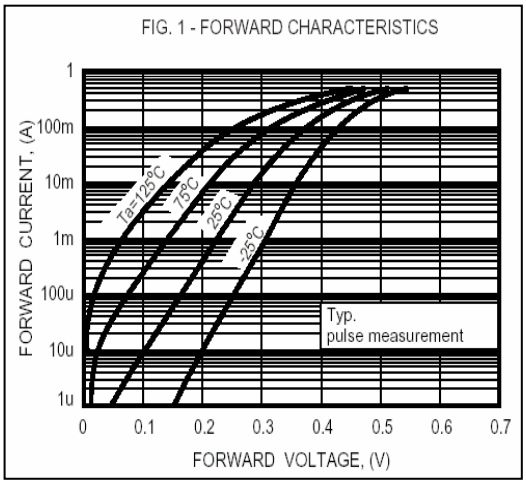
Parameter	Symbol	Ratings	Unit
Junction Temperature	Tj	+125	℃
Storage Temperature	Tstg	-40 ~ +125	℃
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	40	V
Maximum RMS Voltage	V_{RMS}	28	V
Maximum DC Blocking Voltage	V_{DC}	40	V
Peak Forward Surge Current at 8.3mSec single half sine-wave	I_{FSM}	3.0	A
Typical Junction Capacitance between Terminal (Note 1)	C_J	20	pF
Maximum Average Forward Rectified Current	Io	0.5	A
Total Power Dissipation	PD	225	mW

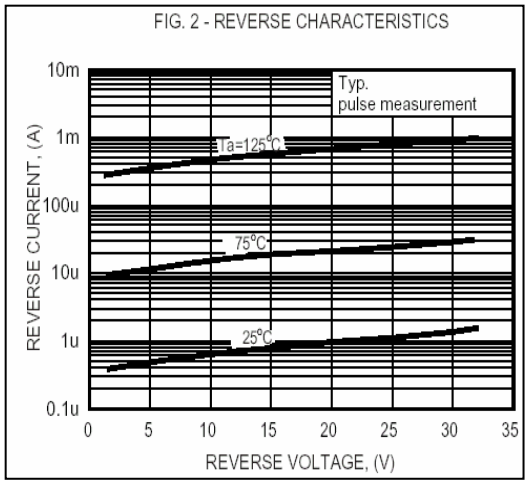
Electrical Characteristics (at T_A = 25℃ unless otherwise noted)

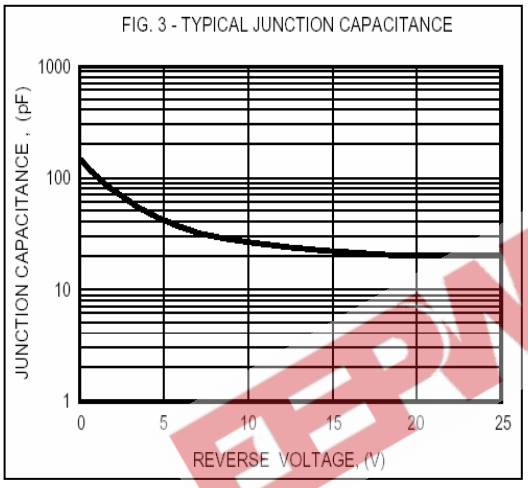
Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Reverse Breakdown Voltage	$V_{(BR)R}$	40	-	-	V	IR=100μA
Maximum Instantaneous Forward Voltage	V_F	-	-	550	mV	IF=500mA
Maximum Average Reverse Current	I_R	-	-	30	μA	VR1=10V
		-	-	50	μA	VR2=30V

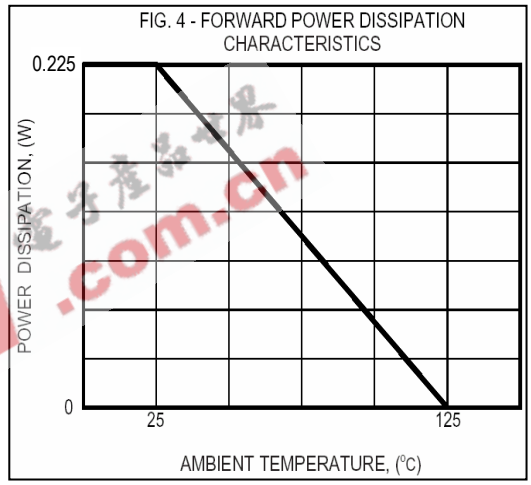
Notes: 1. Measured at 1.0 MHz and applied reverse voltage of 10 volts.
2. ESD sensitive product handling required.

Characteristics Curve









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